

Specifications	
Part Number	RN1105ACT(TPL3)
Manufacturer	Toshiba Semiconductor and Storage
Description	TRANS PREBIAS NPN 0.1W CST3
Category	Discrete Semiconductor Products > Transistors - Bipolar
Part Status	2621 pcs Stock
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	150mV @ 250μA, 5mA
Transistor Type	NPN - Pre-Biased
Supplier Device Package	CST3
Series	-
Resistor - Emitter Base (R2) (Ohms)	47k
Resistor - Base (R1) (Ohms)	2.2k
Power - Max	100mW
Packaging	Tape & Reel (TR)
Package / Case	SC-101, SOT-883
Mounting Type	Surface Mount
Frequency - Transition	-
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V
Current - Collector Cutoff (Max)	500nA
Current - Collector (Ic) (Max)	80mA

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